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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/785,999	02/16/2001		Jay E. Uglow	LAMP1P106A	2171
25920	7590	10/08/2002			
MARTINE	& PENII	LLA, LLP	EXAMINER		
710 LAKEW SUITE 170			PHAM, THANHHA S		
SUNNYVAI	LE, CA 9	4085		ART UNIT PAPER NUMBER	
				2813	1.1
				DATE MAILED: 10/08/2002	11

Please find below and/or attached an Office communication concerning this application or proceeding.

			m
	Application No.	Applicant(s)	
Advisory Acti n	09/785,999	UGLOW ET AL.	
Advisory ried in	Examiner	Art Unit	
	Thanhha Pham	2813	
The MAILING DATE of this communication appe	ears on the cover sheet with the c	correspondence addre	ss
THE REPLY FILED 23 September 2002 FAILS TO PLACE Therefore, further action by the applicant is required to average final rejection under 37 CFR 1.113 may only be either: (1 condition for allowance; (2) a timely filed Notice of Appea Examination (RCE) in compliance with 37 CFR 1.114.	void abandonment of this applica ) a timely filed amendment which	ation. A proper reply to h places the application	o a on in
PERIOD FOR RE	EPLY [check either a) or b)]		
a) $\square$ The period for reply expires $\underline{3}$ months from the mailing date			
b) The period for reply expires on: (1) the mailing date of this no event, however, will the statutory period for reply expire ONLY CHECK THIS BOX WHEN THE FIRST REPLY WAS 706.07(f).  Extensions of time may be obtained under 37 CFR 1.136(a). The fee have been filed is the date for purposes of determining the period of fee under 37 CFR 1.17(a) is calculated from: (1) the expiration date of (2) as set forth in (b) above, if checked. Any reply received by the 0.77	later than SIX MONTHS from the mailing FILED WITHIN TWO MONTHS OF The date on which the petition under 37 CF of extension and the corresponding amount the shortened statutory period for reply ce later than three months after the mail	g date of the final rejection. HE FINAL REJECTION. So R 1.136(a) and the approposition of the fee. The approportionally set in the final Of	ee MPEP riate extension riate extension fice action; or
timely filed, may reduce any earned patent term adjustment. See 37 Co.  1. A Notice of Appeal was filed on Appellant's	s Brief must be filed within the pe	eriod set forth in	
37 CFR 1.192(a), or any extension thereof (37 CFI		if the appeal.	
2. The proposed amendment(s) will not be entered by			
(a) they raise new issues that would require furth		see NOTE below);	
(b) they raise the issue of new matter (see Note because of the second o			alifaina tha
<ul><li>(c)  they are not deemed to place the application i issues for appeal; and/or</li></ul>			
(d)  they present additional claims without cancel	ing a corresponding number of f	inally rejected claims.	
NOTE: <u>See Continuation Sheet</u> .			
3. Applicant's reply has overcome the following reject	ion(s): <u>See Continuation Sheet</u> .		
4. Newly proposed or amended claim(s) would canceling the non-allowable claim(s).	be allowable if submitted in a se	eparate, timely filed ar	nendment
5. ☐ The a) ☐ affidavit, b) ☐ exhibit, or c) ☒ request for application in condition for allowance because: See	reconsideration has been consections	idered but does NOT	place the
6. The affidavit or exhibit will NOT be considered bed raised by the Examiner in the final rejection.	cause it is not directed SOLELY	to issues which were r	newly
7. For purposes of Appeal, the proposed amendment explanation of how the new or amended claims w	t(s) a)⊠ will not be entered or b ould be rejected is provided belo	)∏ will be entered and ow or appended.	d an
The status of the claim(s) is (or will be) as follows:			
Claim(s) allowed: A DHC			
Claim(s) objected to month			
Claim(s) rejected: <u>1-16 and 24</u> .			
Claim(s) withdrawn from consideration: <u>25-29</u> .			
8. The proposed drawing correction filed on is	a) approved or b) disapp	proved by the Examine	∍r.
9. Note the attached Information Disclosure Stateme		A B	
10. Other:	$\ell$	CARL WHITEHEAD, UR. PERVISORY PATENT EXAM	ud l

TECHNOLOGY CENTER 2800

Application No. 009/785,999

## Continuation Sheet (PTO-303)

Continuation of 2. NOTE: claim 27-31 can not be cancelled because claims 27-31 were renumbered by rule 1.126 to claims 25-29 respectively (see Office Action dated 07/18/02 for details).

Continuation of 3. Applicant's reply has overcome the following rejection(s): Rejection under 35 U.S.C 112, Rejection under 35 U.S.C. 102(e) as anticipated by Jain [US 5,821,168].

Continuation of 5. does NOT place the application in condition for allowance because:

Contradict to Applicant agrument on page 10, Smith discloses a trench layer of alow dielectric constant layer (430, fluorinated parylene, col 3 lines 56-62) over a via layer of inorganic dielectric silicon dioxide (424, silicon dioxide by TEOS, col 3 lines 25-27)

Contradict to Applicant agrument on page 11, Wang et al ('735) discloses the claimed method of claims 1-4, 10-16. Wang et al teaches forming an inorganic dielectric layer (SiOF -- silicon dioxide being doped with fluorine, layer 14, fig 2) to define a via dielectric layer over the barrier layer, the inorganic dielectric layer being highly selective relative to the barrier layer when being etch (see fig 8 wherein the inorganic dielectric layer 14 to define a via dielectric layer is selective etched with respect to the barrier layer 12) and forming a low dielectric layer (organic low k dielectric BCB, layer 18) to define a trench dielelectric layer over the inorganic dielectric layer. Therefore, Wang ('735) teaches each and every feature of Applicant's claimed invention.

Contradict to Applicant argument on page 11, Wang et al ('577) teaches the low dielectric constant trench layer (30, e.g. BCB, fig 7, col 5 lines 63-67 and col 6 lines 1-2) over an inorganic dielectric via layer (24, silicon dioxide, fig 3, col 5 lines 32-35) wherein the inorganic dielectric layer beng highly selective to the barrier when being etched Therefore, Wang ('577) teaches each and every feature of Applicants's claimed invention.